Electronic Supplementary Material (ESI) for Nanoscale.

Effectively Modulating Vertical Tunneling Transport by Mechanically Twisting Bilayer Graphene within All-metallic Architecture

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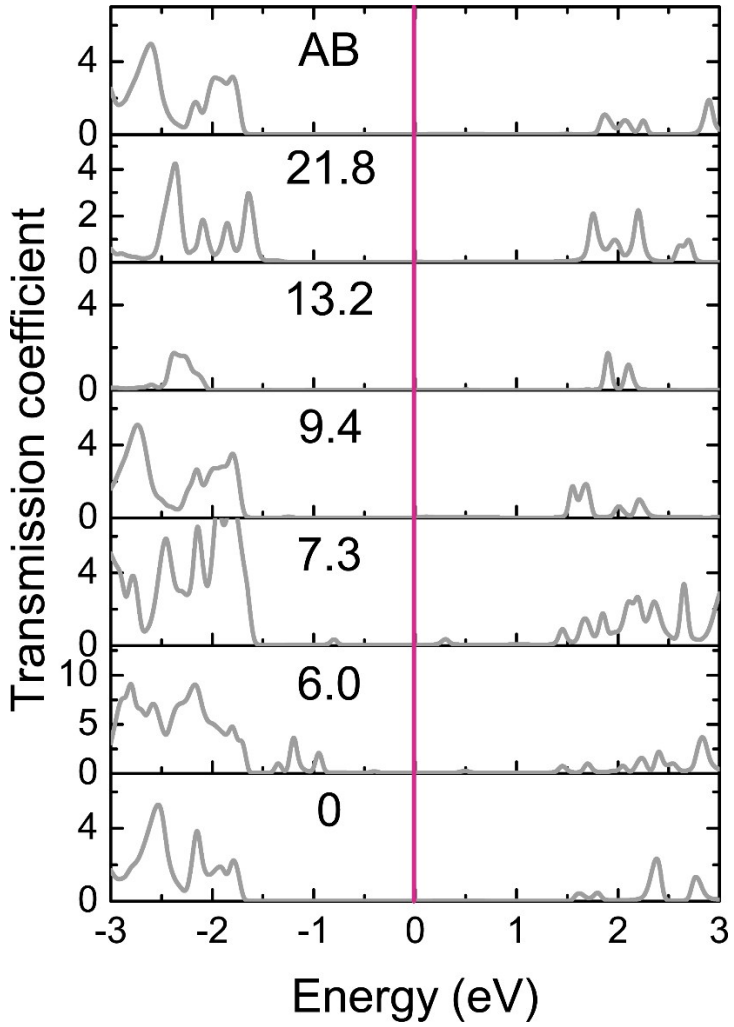

Fig. S1. The transmission spectra at high symmetry point K for each interlayer twist angle.

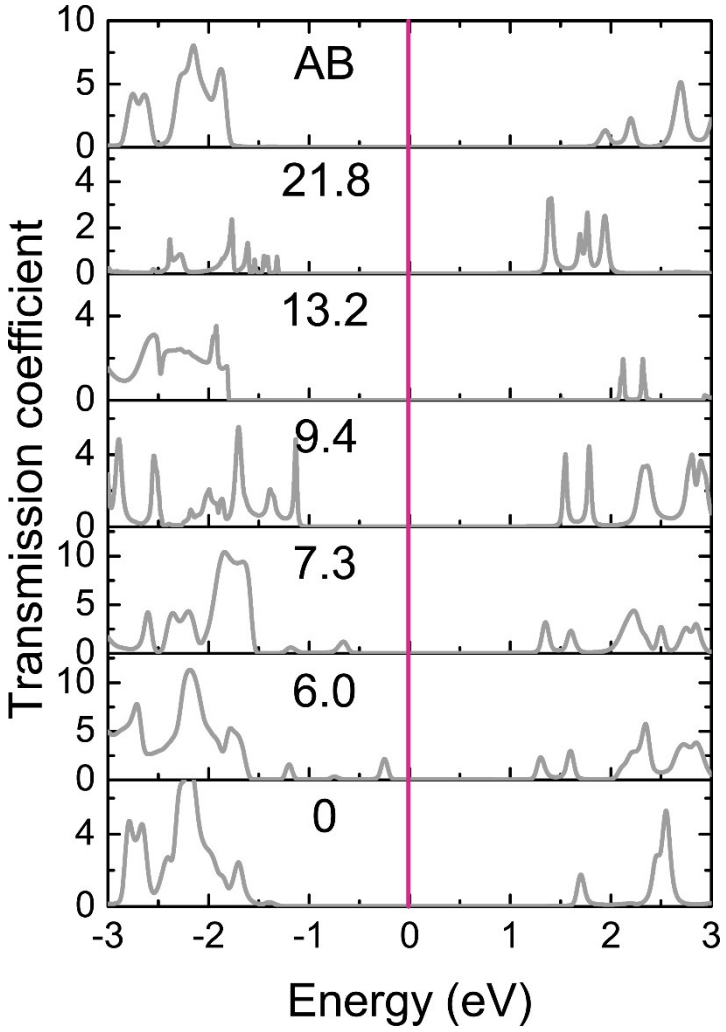

Fig. S2. The transmission spectra at high symmetry point Gamma for each interlayer twist angle.

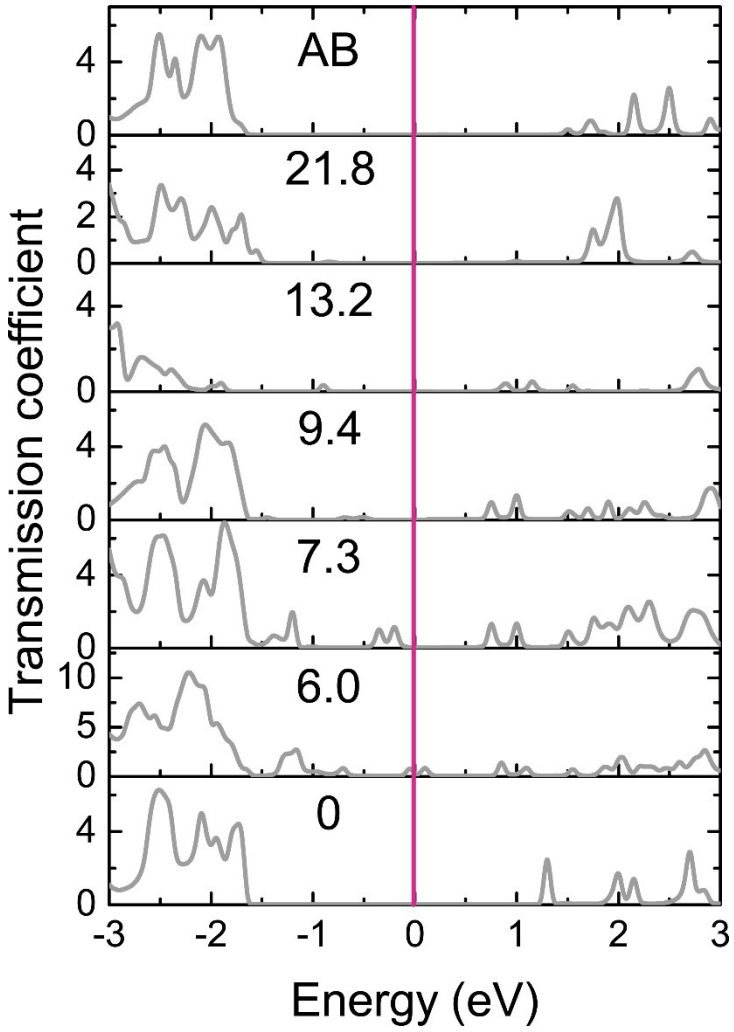

Fig. S3. The transmission spectra at high symmetry point M for each interlayer twist angle.

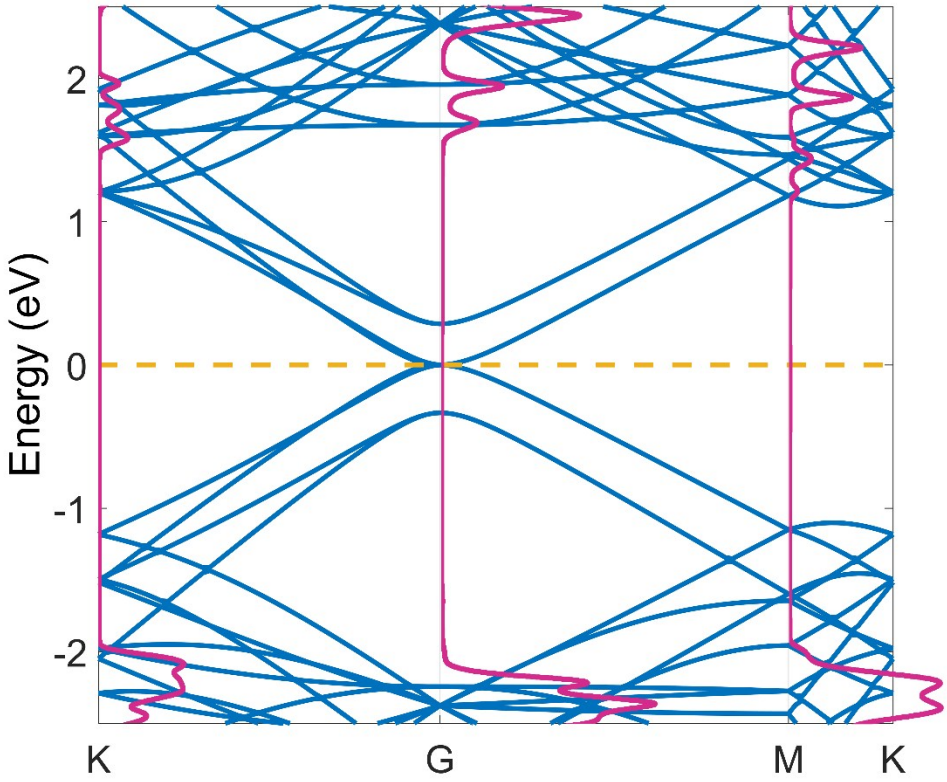

Fig. S4. The electronic band structure of AB-stacking bilayer graphene and its corresponding transmission spectra (purple line) at high symmetry point (Gamma, K and M) which is shifted to match the eigenvalue in the electronic band structure, respectively. The amplitude of transmission probabilities is adjusted to a uniform scale to facilitate comparison.

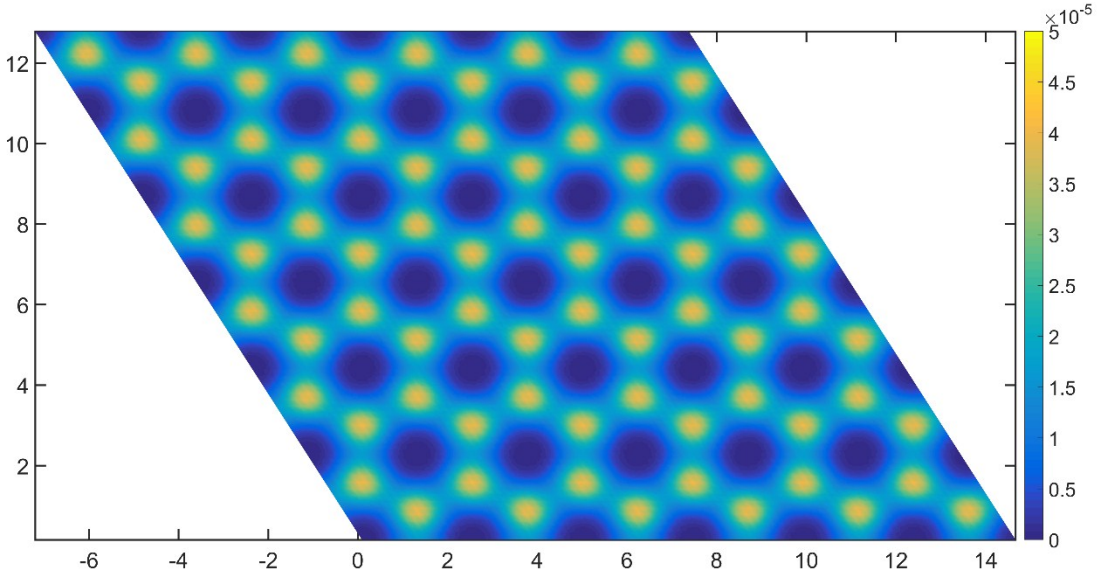

Fig. S5. The projected density of states on XY plane in the middle position between bilayer graphene at Fermi energy level (E=0 eV) for 0° interlayer twist angle.

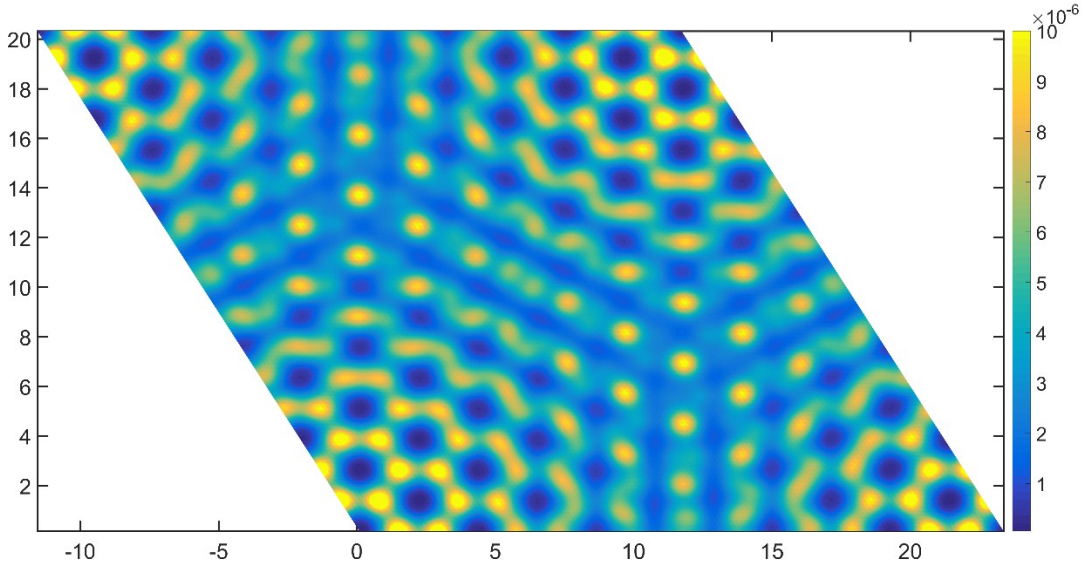

Fig. S6. The projected density of states on XY plane in the middle position between bilayer graphene at Fermi energy level (E=0 eV) for 6° interlayer twist angle.

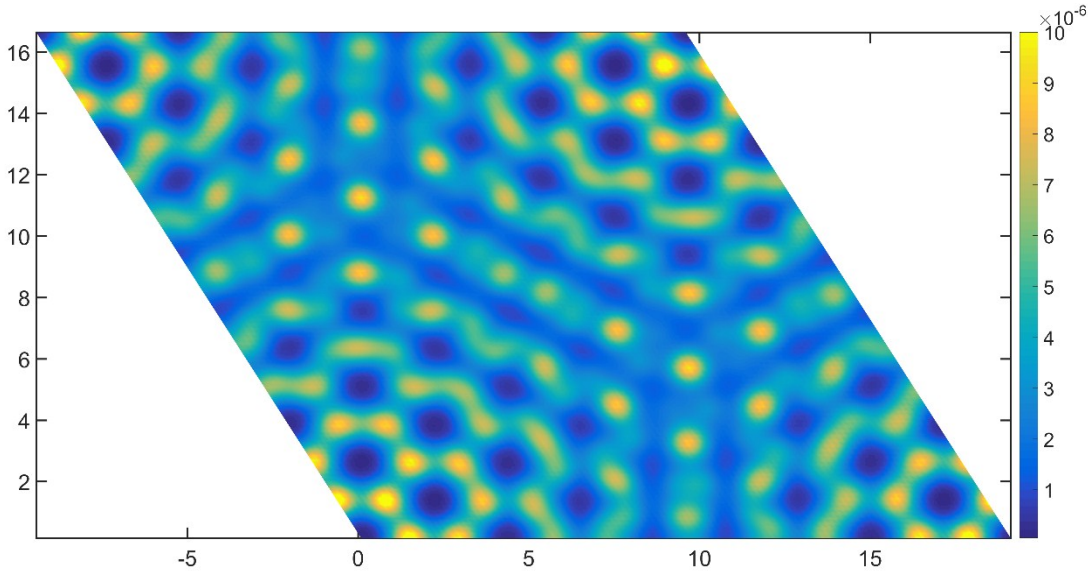

Fig. S7. The projected density of states on XY plane in the middle position between bilayer graphene at Fermi energy level (E=0 eV) for 7.3° interlayer twist angle.

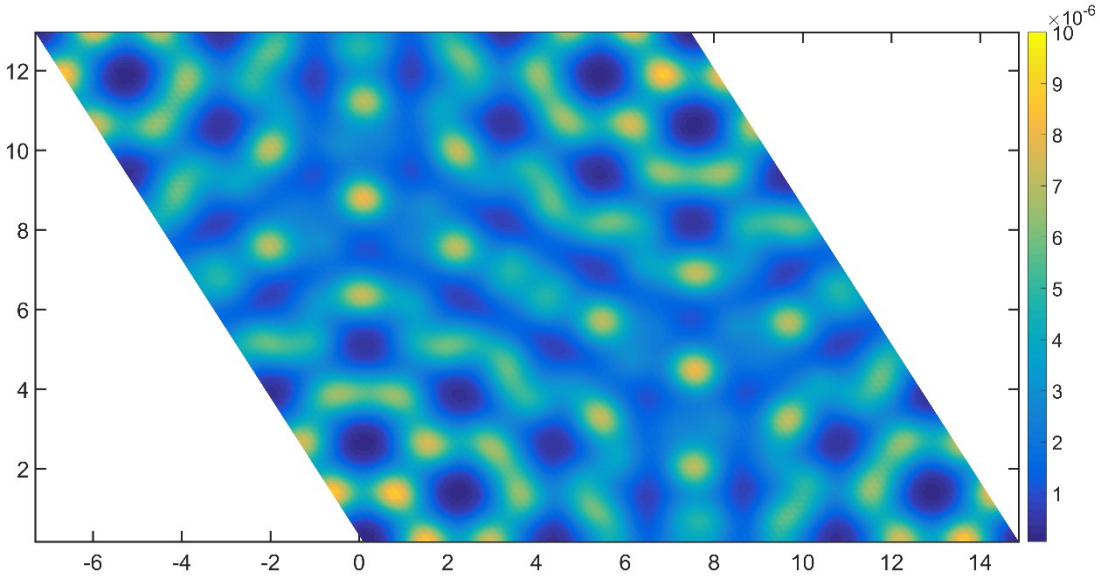

Fig. S8. The projected density of states on XY plane in the middle position between bilayer graphene at Fermi energy level (E=0 eV) for 9.4° interlayer twist angle.

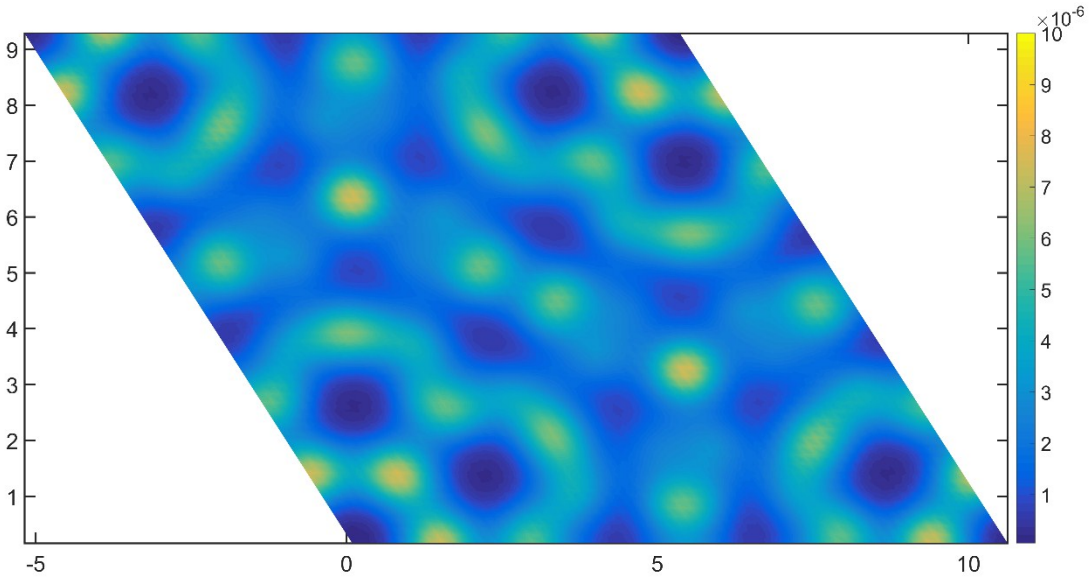

Fig. S9. The projected density of states on XY plane in the middle position between bilayer graphene at Fermi energy level (E=0 eV) for 13.2° interlayer twist angle.

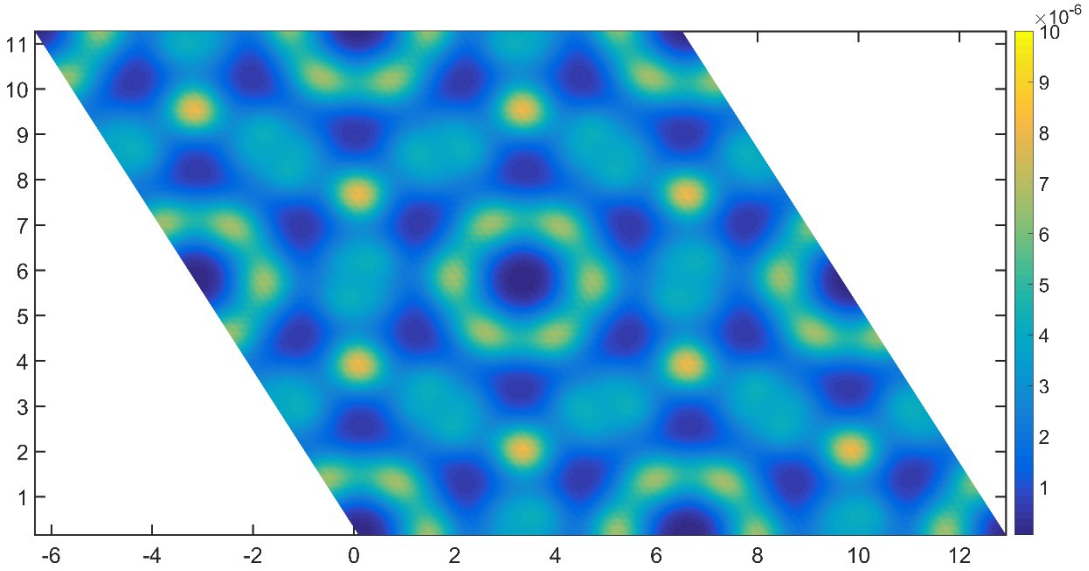

Fig. S10. The projected density of states on XY plane in the middle position between bilayer graphene at Fermi energy level (E=0 eV) for 21.8° interlayer twist angle.